

10/019244

JC13 Rec'd PCT/PTO 21 DEC 2001

FORM PTO-1449 (Modified)

ATTY. DOCKET NO.

SERIAL NO.

**LIST OF PATENTS AND PUBLICATIONS FOR
APPLICANT'S INFORMATION
DISCLOSURE STATEMENT**

1446NP

To Be Assigned

(Use several sheets if necessary)

FILING DATE:

GROUP:

14

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIALS	DOCUMENT NUMBER						DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPRO.)
AK	4	9	9	3	3	5	7	02/19/91	Scholz	118	715
AK	5	2	4	2	5	3	0	09/07/93	Batey et al.	156	613
AK	5	2	5	6	2	0	5	10/26/93	Schmitt, III et al.	118	723
AK	5	2	8	1	2	7	4	01/25/94	Yoder	118	697
AK	5	3	1	6	7	9	3	05/31/94	Wallace et al.	427	208.1
AK	5	3	4	2	6	6	0	08/30/94	Cann et al.	427	577

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation
		0 0 1 5 3 9 0	17.09.80	EPO	—	—	

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

Hurle, D.T.J., "Thin Films and Epitaxy," Handbook of Crystal Growth, Vol. 3, 1994, pp. 606-663.

Liu, H. et al., "GaAs Atomic Layer Epitaxy in a Rotating Disc Reactor," SPIE, Vol. 1676, 1992, pp. 20-25.

EXAMINER

DATE CONSIDERED

11/25/03

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	1446NP	To Be Assigned
	<p>APPLICANT: Prasad Narhar GADGIL</p>	
	FILING DATE: Herewith	GROUP: To Be Assigned

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✓ McIntosh, F.G. et al., "Silicon Monolayer Growth Using Dichlorosilane and Hydrogen in a Near Atmospheric Pressure Chemical Vapor Deposition Reactor," *Thin Solid Films* 225, 1993, pp. 183-186.

✓ Reid, K.G. et al, "The Role of Gas Phase Decomposition in the Ale Growth of III-V Compounds," North Carolina State University, Electrical & Computer Engineering Dept., Raleigh, NC., pp. 133-138.

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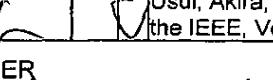
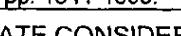
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OTHER ART (including Author, Title, Date, Pertinent Pages, etc.)

<input checked="" type="checkbox"/> ✓ <input checked="" type="checkbox"/> ✓	<p>Suñakeris, J. et al., "Layer-by-Layer Epitaxial Growth of GaN at Low Temperatures," <i>Thin Solid Films</i>, 1993, pp. 244-249.</p> <p>Usui, Akira, "Atomic Layer Epitaxy of III-V Compounds: Chemistry and Applications," <i>Proceedings of the IEEE</i>, Vol. 80, No. 10, October 1992, pp. 1641-1653.</p>
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